

#### SSC8334GSB

#### **Dual N-Channel Enhancement MOSFET**

#### > Features

VDS	VGS	RDSON Typ.	ID	ESD
30V	±12V	450mR@4V5	1A	1.2KV
		520mR@2V5		

### > Description

SSC8334GSB uses advanced trench technology to provide excellent RDSON and low gate charge. The complementary MOSFETS may be used to form a level shifted high side switch, and for a host of other applications.

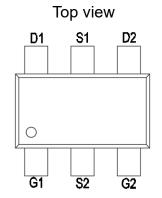
# Applications

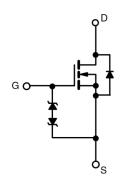
- Small signal switch
- Load switch
- Digital Transistors

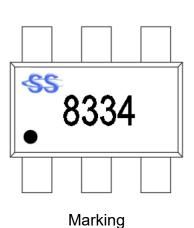
#### > Ordering Information

Device	Package	Shipping
SSC8334GSB	SOT23-6L	3000/Reel

# Pin configuration







www.sscsemi.com Rev.1.1



# ➤ Absolute Maximum Ratings(T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
$V_{DSS}$	Drain-to-Source Voltage	30	V
$V_{GSS}$	Gate-to-Source Voltage	±12	V
I <sub>D</sub>	Continuous Drain Current <sup>a</sup>	1	А
I <sub>DM</sub>	Pulsed Drain Current <sup>b</sup>	3	А
$P_{DSM}$	Power Dissipation <sup>a</sup>	0.8	W
P <sub>D</sub>	Power Dissipation °	0.3	W
TJ	Operation junction temperature	-55 to 150	°C
T <sub>STG</sub>	Storage temperature range	-55 to 150	

# ➤ Thermal Resistance Ratings(T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Typical	Unit
R <sub>0JA</sub>	Junction-to-Ambient Thermal Resistance <sup>a</sup>	420	°C/W
R <sub>eJC</sub>	Junction-to-Case Thermal Resistance	160	C/ VV

#### Note:

- a. The value of R<sub>θJA</sub> is measured with the device mounted on 1 in² FR-4 board with 2oz.copper,in a still air environment with T<sub>A</sub>=25°C. The value in any given application depends on the user is specific board design. The current rating is based on the t≤ 10s thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation  $P_D$  is based on  $T_{J(MAX)}$ =150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

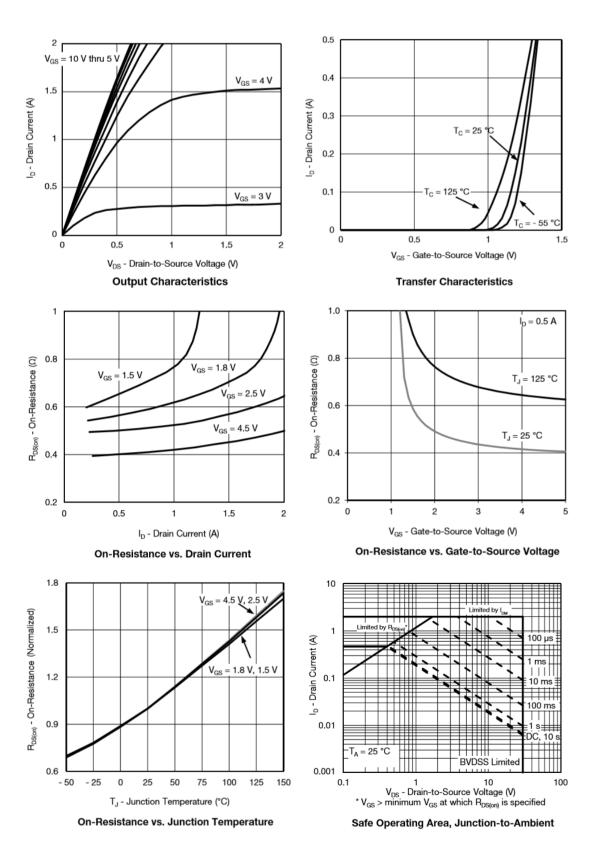


# ➤ Electronics Characteristics(T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур.	Max	Unit	
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	VGS=0V, ID=250uA	30			>	
V <sub>GS</sub> (th)	Gate Threshold Voltage	VDS=VGS, ID=250uA	0.6	1	1.3	V	
		VGS=4.5V, ID=1A		450	700		
R <sub>DS(on)</sub>	Drain-Source On- Resistance	VGS=2.5V, ID=1A		520	900	mR	
	Resistance	VGS=1.8V, ID=0.5A		950	1500		
I <sub>DSS</sub>	Zero Gate Voltage  Drain Current	VDS=24V, VGS=0V			1	uA	
I <sub>GSS</sub>	Gate-Source leak	VGS=±10V, VDS=0V			±10	uA	
G <sub>FS</sub>	Transconductance	VDS=5V, ID=1A		1		S	
V <sub>SD</sub>	Forward Voltage	VGS=0V, IS=1A		0.9	1.3	V	
Ciss	Input Capacitance			62			
Coss	Output Capacitance	VDS=15V, VGS=0V,		16		pF	
Crss	Reverse Transfer  Capacitance	f=1MHZ		4			
Qg	Total Gate Charge	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\		1			
Qgs	Gate Source Charge	VDS=15V, VGS=4.5V,		0.3		nC	
Qgd	Gate Drain Charge	ID=3.8A		0.2			
T <sub>D(ON)</sub>	Turn-on delay time			3			
Tr	Rise time	VDS=15V, VGS=6V,		14			
T <sub>D(OFF)</sub>	Turn-off delay time	RL=30R, RGEN=1R		11		ns	
Tf	Fall time			9			

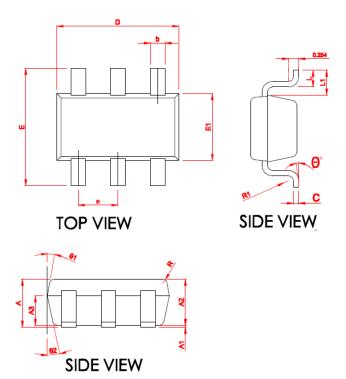


# ➤ N-Channel Typical Characteristics(T<sub>A</sub>=25°C unless otherwise noted)





### Package Information



	MILLIMETER			
SYMBOL				
J	MIN	NOM	MAX	
Α	1.06	1.15	1.24	
* A1	0.01	0.05	0.09	
* A2	1.05	1.10	1.15	
A3	0.65	0.70	0.75	
* b	0.30	0.35	0.45	
* с	0.117	0.127	0.157	
* D	2.87	2.92	2.97	
* E	2.72	2.80	2.88	
* E1	1.55	1.60	1.65	
* е	0.90	0.95	1.00	
* L	0.32	0.40	0.48	
* L1	0.55	0.60	0.65	
R	0.10 REF			
R1	0.12 REF			
<b>*</b> θ	0	-	8°	
θ1	8°	10°	12°	
θ2	10°	12°	14°	

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